

TDA7336

STEREO PREAMP + AMS + DOLBY B* NOISE REDUCTION PROCESSOR

- DUAL CHANNEL PROCESSOR FOR PLAY-BACK APPLICATIONS.
- STEREO DOLBY B NR SYSTEM
- LOW NOISE HEAD PREAMPLIFIER
- MUTE, AMS (AUDIO MUSIC SENSOR)
 FUNCTIONS
- INTERNAL SWITCHES FOR EQUALIZATION
- DOLBY REFERENCE LEVEL -6dBm (388.2mVrмs)
- MINIMUM NUMBER OF EXTERNAL COMPO-NENTS
- LOW SUPPLY CURRENT (18mA)
- MIXED BIPOLAR/CMOS TECHNOLOGY

DESCRIPTION

The TDA7336 is a monolithic BICmos IC designed for use in stereo cassette player systems.

The device includes two separate audio channels composed by low noise preamplifier, Dolby B noise reduction system and Audio Music Sensor.

The dual preamplifier contains mute, metal/normal facilities for amplification of low level signal in applications requiring very low noise performances

Each channel consists of two cascaded operational amplifiers.

The first one, AMP1, has a fixed gain of 36dB, and allows magnetic heads connection directly to ground. The second one, AMP2, is a standard operational amplifier whose equalizing external components fix the frequency response.

The Audio Music Sensor circuit detects the interprogram space and then the starting point of musical programs (the interprogram time and program detection time are externally selectable).

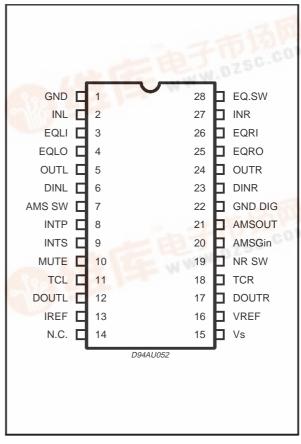
The device contains Dolby B decoder NR chains requiring very few external components and do not require coils.

* Dolby B and the Double-D symbol are trademarks of Dolby Laboratories Licensing Corporation, San Francisco, California 94103-4813, USA.

This device is available only to Licensing and application information may be obtained from Dolby Lab.



PIN CONNECTION (Top view)





TDA7336

ABSOLUTE MAXIMUM RATINGS

Symbol	Parameter	Value	Unit
Vs	Supply Voltage	12	V
Ptot	Total Power Dissipation	1	W
Top	Operating Temperature Range	-40 to 85	°C
T _{stg}	Storage Temperature Range	-40 to 150	°C

THERMAL DATA

Rthi-pins I nermal resistance junction-pins 85 °C/VV	Rth j-pins	Thermal resistance junction-pins	85	°C/W
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PIN FUNCTIONS

N.	Name	VDC (V)	Function
1	GND		Ground
2	IN L	0	Preamplifier Left Input
3,26	EQLI, EQRI	4.6	Equalizer Inputs
4, 25	EQLO, EQRO	4.6	Equalizer Outputs
5, 24	OUTL, OUTR	4.6	Preamplifier Outputs
6, 23	DINL, DINR	V_{ref}	Dolby NR Inputs
7	AMS SW	5.6	Audio Music Sensor Switch (ON/OFF) HIGH = ON
8	INTP		Interprogram Time Constant ("Signal Detection")
9	INTS		Interspace Time Constant ("Blank Detection")
10	MUTE		Mute Switch ON = LOW (2)
11, 18	TLC, TCR	0.4	Dolby Time Constants
12, 17	DOUTL, DOUTR	V_{ref}	Dolby Outputs
13	lref	1.2	Reference Current Source
15	Vs		Positive Power Supply
16	Vref	V _S /2	Reference Voltage
19	NR SW		Noise reduction ON/OFF: HIGH =OFF (2)
20	AMS GIN	1.4	Audio Music Sensor Input Pin
21	AMS OUT		Audio Music Sensor Output Pin (open collector configuration, see Fig. 2)
22	GND DIG.	0	Digital Ground
27	IN R	0	Preamplifier Right Input
28	EQ SW	0	Equalizer Switch (Low = normal position High = metal position)

⁽²⁾ Internal pull-up resistor (digital high level if pin left open)

Figure 1: Application Circuit

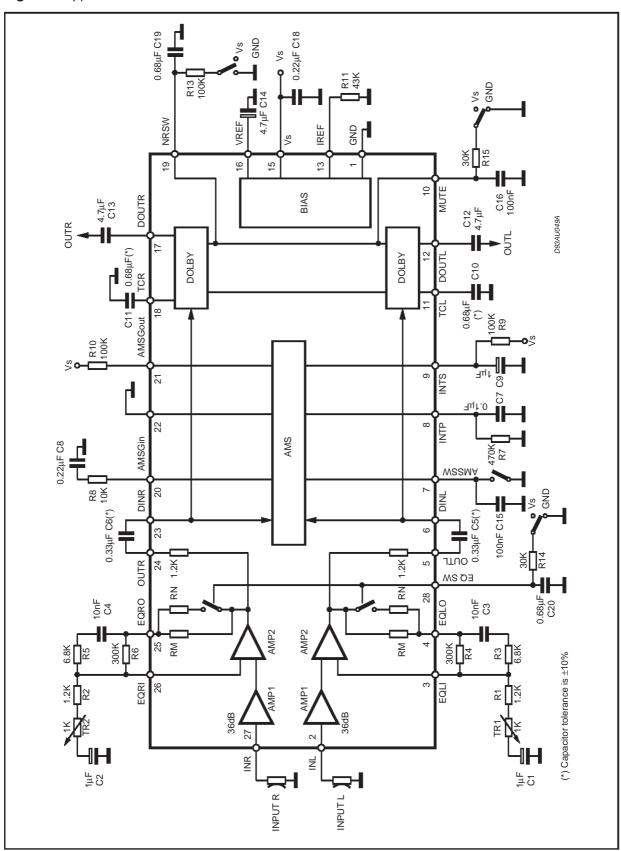


Figure 1a: Components & Top Copper Layer of the Fig. 1 (1:1 scale).

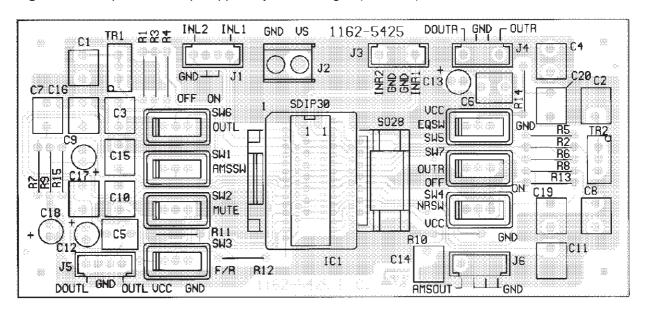
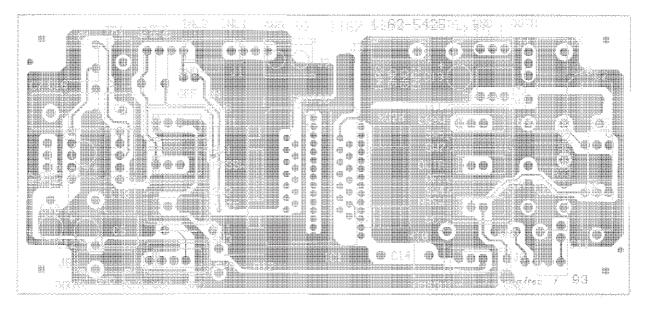
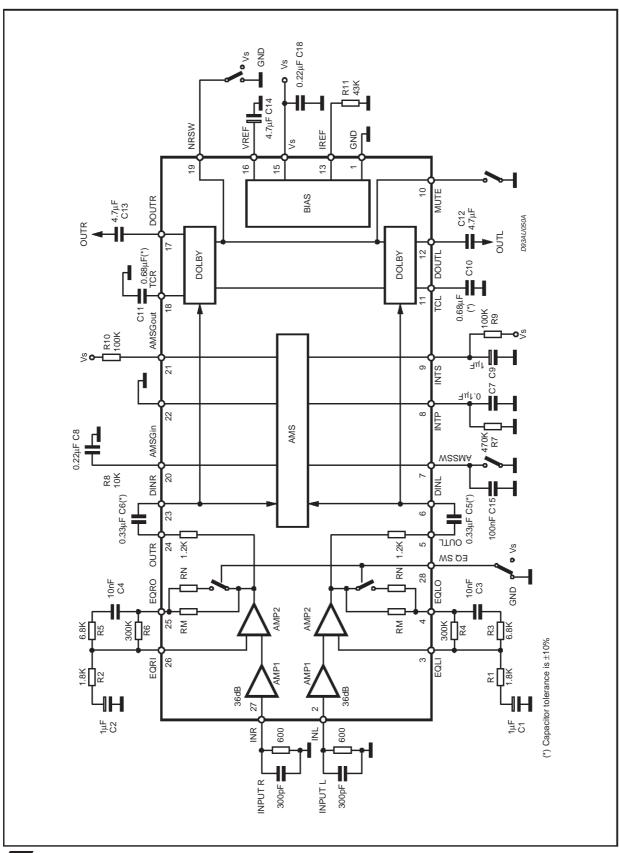


Figure 1b: Bottom Copper Layer of the Fig. 1 (1:1 scale).



TEST CIRCUIT



ELECTRICAL CHARACTERISTICS (Vs = 8.5V; f = 1KHz; $R_g = 600\Omega$ $T_{amb} = 25^{\circ}C$; R11 = 43K Ω all level referenced to -6dBm/400Hz, at Dout with NR SW OFF; unless otherwise specified see application circuit of Fig. 1) NAB METAL position.

SUPPLY

Symbol	Parameter	Test Cond	Test Condition		Тур.	Max.	Unit
Vs	Supply Voltage			8	8.5	10.5	V
Is	Supply Current			11	18	26	mA
Vref	Reference Voltage (pin 16)			4	4.3	4.6	V
VDC	DC Voltage pin 13 (R ₁₁ = 43K)		1.15	1.25	1.35	V	
SVR	Ripple Rejection (Input Referred)	V _{ripple} = 0.3Vrms f _{ripple} = 1KHz	Dolby OFF Dolby ON	80 85	90 95		dB dB
MUTEth	Mute Threshold Pin 10	ON OFF		0 2.0		0.8 Vs	V
IMUTE	Mute Current				10	20	μΑ
MUTEA	Mute Attenuation			55	65		dB

PREAMPLIFIER

Rı	Input Resistance	(pin 2, 27)	30	50	70	ΚΩ
l _l	Input Bias Current				10	μΑ
G۷	Closed Loop Gain	pin 3, 4 and 25, 26 shorted	32.5	35.5	38.5	dB
ΔGv	Closed Loop Gain Match		-1		1	dB
Rм	Resistance Metal Position		4.35	5.8	7.25	KΩ
R _N	Resistance Normal Position		50	160	300	Ω
ем	Total Input Noise	Unw. B= 20Hz to 20KHz $R_g = 0\Omega$; $R_g = 600\Omega$; A weighted $R_g = 600\Omega$;		0.45 0.8 0.5		μV μV μV
Ro	Output Impedance	(Pin 5, 24)	0.9	1.2	1.7	ΚΩ
EQı	Normal Low Level (pin 28)		0		1.5	V
EQh	Metal High Level (pin 28)		3.5		Vs	V
ΔR_{M}	Metal Resistance Matching		-2	0	+2	%

AUDIO MUSIC SENSOR

IAMSout	AMS Output Current				5	mA
VAMSout	AMS Output Low Level	IAMout = 2mA		200	800	mV
R _P 20	Input Impedance		0.8	1.1	1.4	ΚΩ
AMSswl	AMS OFF Low Level		0		0.8	V
AMSswh	AMS ON High Level		2		VS	V
VTH1	Interprogram Threshold Voltage	(pin 8)	1.2	1.45	1.7	V
VTH ₂	Interspace Threshold Voltage	(pin 9)	4	4.3	4.6	V
AMSth	AMS Threshold Level	see note (3)	0.6	1	1.4	V
IAMSsw	AMS Switch pin Current		5	10	15	μΑ

DOLBY SECTION

G۷	Voltage Gain	f = 1KHz;	OFF	-1	0	1	dB
ΔGv	Gain Matching		OFF	-0.5		0.5	dB
RDı	Dolby Input Res.	(pin 6, 23)		46	63		KΩ
S/H	Signal Handling	Vs = 8V; THD = 1%	OFF	12	13		dB
R _{DO}	Dolby Output Imp.	(pin 12, 17)		100	200	300	Ω
B DEC 1	Decode Out	f = 10KHz; Vı = 0.4dB	ON	-1.5	0	1.5	dB

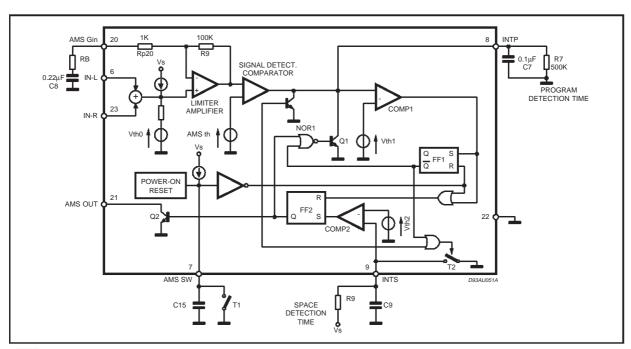
ELECTRICAL CHARACTERISTICS (continued) **DOLBY SECTION**

Symbol	Parameter	Test Condition	DOLBY	Min.	Тур.	Max.	Unit
B DEC 2	Decode Out	f = 500Hz; Vı = -22.1dB	ON	-26.5	-25	-23.5	dB
B DEC 3	Decode Out	f = 2KHz; V1 = -18dB	ON	-26.5	-25	-23.5	dB
B DEC 4	Decode Out	f = 5KHz; V _I = -29.7dB	ON	-41.5	-40	-38.5	dB
B DEC 5	Decode Out	f = 10KHz; V ₁ = -29.6dB	ON	-41.5	-40	-38.5	dB
NRı	Dolby ON Low Level Pin 19			0		0.8	V
NRh	Dolby OFF High Level Pin 19			2		Vs	V

GENERAL (PREAMPLIFIER + DOLBY)

Symbol	Parameter	Test Condition	Min.	Тур.	Max.	Unit
THD	Total Harmonic Dist.	Vo = 0dB; f = 1KHz Dolby OFF		0.02	0.1	%
		Vo = 0dB; f = 1KHz Dolby ON		0.05	0.1	%
		Vo = 0dB; f = 10KHz Dolby OFF		0.03		%
		Vo = 0dB; f = 10KHz Dolby ON		0.08		%
S/N	Signal to Noise Ratio	$R_g = 600\Omega$; $Vo = 0dB$; Unweighted; Dolby OFF		63		dB
		$R_g = 600\Omega$; $V_O = 0$ dB; Unweighted; Dolby ON		70		dB
		R _g = 600Ω; Vo = 0dB; CCIR/ARM; Dolby OFF	54	63		dB
		$R_g = 600\Omega$; $V_O = 0$ dB; CCIR/ARM; Dolby ON	56	72		dB
Cs	Channel Separation	$R_g = 600\Omega$; $f = 1$ KHz Dolby OFF	50	64		dB
		$R_g = 600\Omega$; $f = 1$ KHz Dolby ON		70		dB
Ст	Channel Cross Talk	$R_g = 600\Omega$; $f = 1$ KHz Dolby OFF	56	70		dB
		$R_g = 600\Omega$; $f = 1$ KHz Dolby ON		75		dB

Figure 2: Audio Music Sensor



AUDIO MUSIC SENSOR (See Figure 2)

Aim of this section is to detect interprogram spaces present on a recorded tape.

Both the blanks (interprogram spaces) and the programs minimum detectable durations can be easily set by means of 2 external and independent time constants.

Also the minimum detectable input signal level can be externally adjusted, by a dedicated gain network.

Main blocks are:

- Variable gain limiter amplifier
- Signal detector circuitry
- Logic blocks able to avoid unproper operations.

Operations Description (refer to the simplified schematic of Figure 2).

- a)The two channels left and right mean signal coming from the preamp chain (AC coupled) are added (current) at the AMS input and presented to the limiter amplifier. The limiter amplifier gain is internally fixed to 40dB, and it could be reduced by the R8 external resistor. The AMSVth threshold is fixed at 1V. The following signal detector comparator informs of the presence of music signal (High level out) and avoids the erroneous detection of very low signal (like noise) as real program.
- b)The system moves in blank detection mode everytime the supply is turned on or, with power supplied, the AMS On/Off pin (to be driven by an open collector output) is turned off (T1 open). Once this condition has happened, the capacitor C15 charges, defining a minimum reset time, long enough to reset the Flip-Flops FF1 and FF2 and to descharge the program detector external C7 capacitor. The charging current at the AMS SW pin is about 10μA. It follows that the reset time (C15 x Vpin7)/IC15 is given approximately by 0.122 x C15 ns where C15 is in μF.
- c)From now on where the sum input signal (leftright) amplified by the limiter exceeds the sig-

nal detector threshold (3) the capacitor C_7 is forced to charge. When the voltage across this capacitor reaches the comparator COMP1 threshold voltage V_{th1} (approx. 2 V_{be}) FF1 is set and FF2 is reset. (4) It follows that Q_1 is turned on discharging the program detection capacitor (C_7) .

d)Always when there is a recorded zone, Q₁ is on; it becomes off only if a blank section is reached. When, with a time constant controlled by the R₉, C₉ network the voltage at space detection time pin reaches Vth₂ threshold (comparator COMP₂) a true blank section is detected and the FF₂ is set. (The minimum charging time is approximately given by:

In this condition Q2 is on, forcing the open collector AMS output to go low, informing the user that a true blank section has been detected. The state is then able to start from the above point c). Figures 3-4 show the signal behaviour.

The device is able to prevent false interspace detection and the end of the tape. (see Fig. 4).

Note

(3): minimum RMS input signal is given by:

$$V_{in} = AMSVth \cdot \frac{1K + R_8}{101K + R_8} \cdot 0.6$$

where Vin is the mean of left and right channels::

$$V_{in} = \frac{V_{right} + V_{left}}{2}$$

(4): the charging current at pin 8 is about 20μA (half input signal) so program detection time constant is given by:

$$\frac{C_7 \times 2V_{be}}{20\mu A} = 70 \times C_7 [\mu F] = [msec]$$

It is recommended to insert a resistor (R7) high enough to prevent fast C7 capacitor discharging.

Figure 3: AMS Timing Diagram

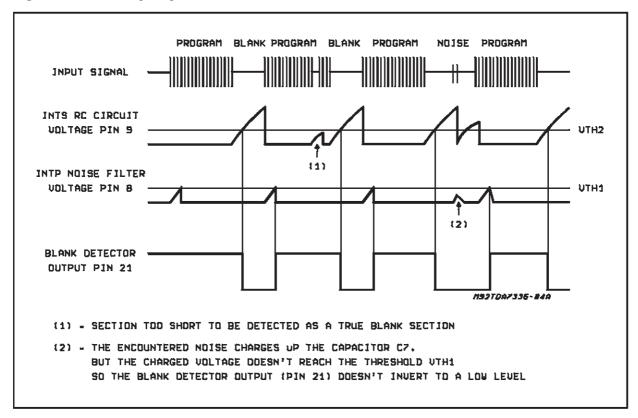
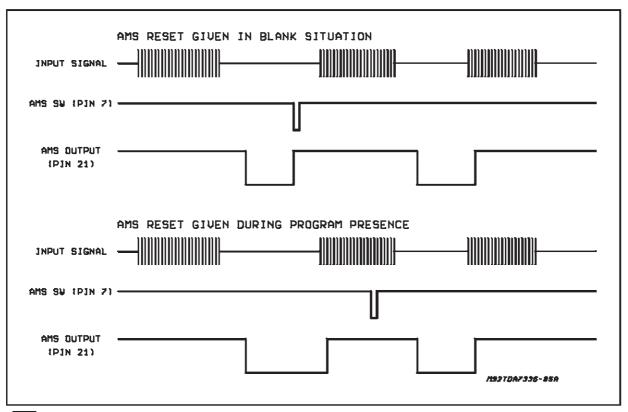


Figure 4



ELECTRICAL COMPONENT DESCRIPTION (see figure 1)

	COMPONENT	RECOMMENDED VALUE	PURPOSE
P R E A M	TR ₁ ,TR ₂ C ₁ , C ₂ C ₃ , C ₄ R ₁ , R ₂ R ₃ , R ₅ R ₄ , R ₆	1ΚΩ 1μF 10nF 1.2ΚΩ 6.8ΚΩ 300ΚΩ	Left/Right Channel IN/OUT equalizer filter TR fixes the gain 150msec NORMAL 70μsec METAL
	C ₅ , C ₆	0.33μF ±10%	Preamplifier out to Dolby B input coupling capacitor
	R ₈ C ₈	10KΩ 0.22μF	Define the AMS input threshold level $V_{in} \cdot \frac{101K + R_8}{1K + R_8} \cdot 1.5 > 1V$ where $V_{in} = (V_{right} + V_{left})/2$
A M S	R7 C7	470KΩ 0.1μF	Set the interprogram detection time: INTP = $70 \times 10^{-3} \times \text{ Cr}[\mu\text{F}] = [\text{sec}]$
	R9 C9	100KΩ 1μF	Set the interspace detection time: INTS = 0.69 x C ₉ x R ₉ sec
	C15	100nF	It fixes music search reset time; Tres = 0.122 x C ₁₅ [μF] = [sec] if C ₁₅ expressed in μF
_	C ₁₀ , C ₁₁	0.68μF ±10%	Dolby output coupling capacitors
D O	C ₁₂ , C ₁₃	4.7μF ±10%	Dolby time constants
L	C ₁₄	4.7μF	Reference voltage external capacitor
B Y	R ₁₁	43ΚΩ	It fixes the I _{ref} current
'	C ₁₆ R ₁₆	0.1μF 30KΩ	If fixes the mute time (typ 10msec).

PINS DESCRIPTION: Internal Configuration

Figure 5: PINS: 2 - 27

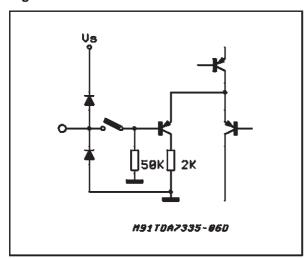
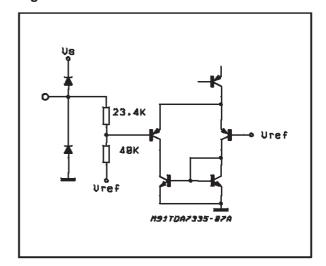


Figure 6: PINS: 6 - 23



PINS DESCRIPTION: Internal Configuration

Figure 7: PINS: 12 - 17

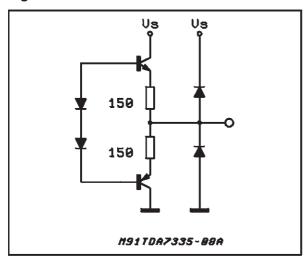


Figure 8: PIN: 8

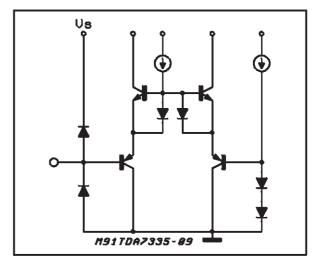


Figure 9: PINS: 3 - 26

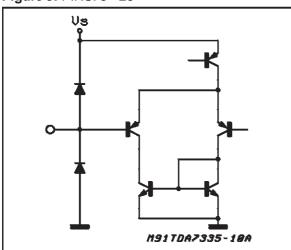


Figure 10: PINS: 4 - 25

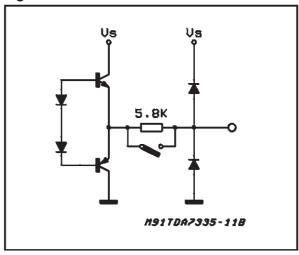


Figure 11: PINS: 5 - 24

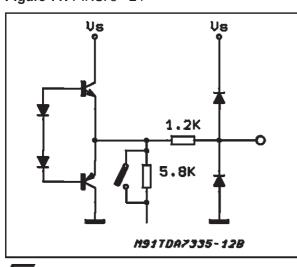
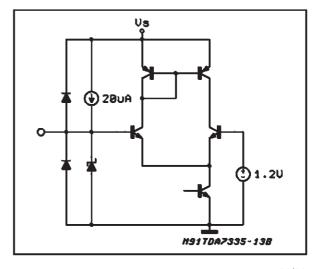


Figure 12: PINS: 7



PINS DESCRIPTION: Internal Configuration

Figure 13: PINS: 11 - 18

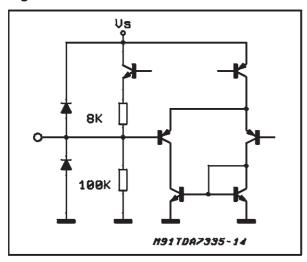


Figure 14: PIN: 13

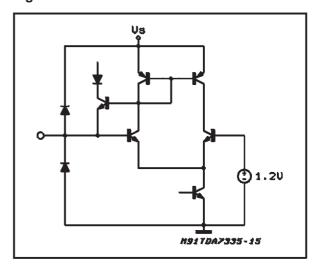


Figure 15: PIN: 9

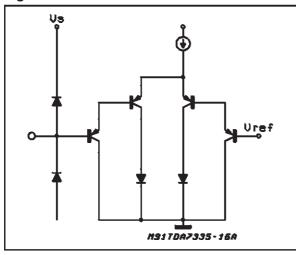


Figure 16: PIN: 21

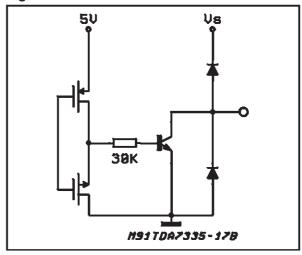


Figure 17: PIN: 20

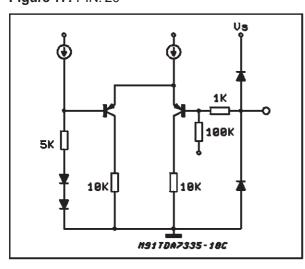
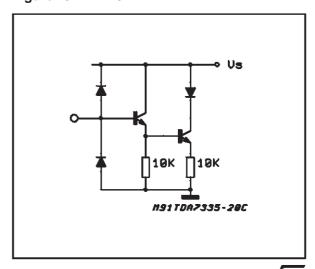


Figure 18: PIN: 28



PINS DESCRIPTION: Internal Configuration

Figure 19: PIN: 19 - 10

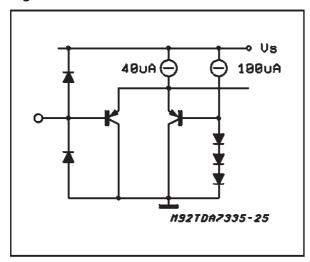
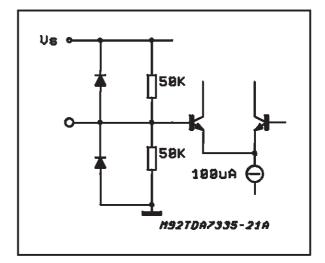


Figure 20: PIN: 16



DEVICE CHARACTERISTICS

Figure 21: Quiescent Current vs. Supply Voltage

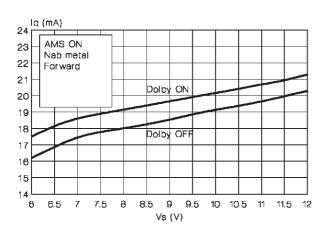


Figure 22: Quiescent Current vs. Temperature

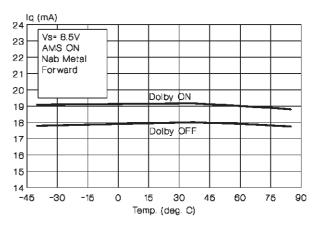


Figure 23: THD vs Supply Voltage

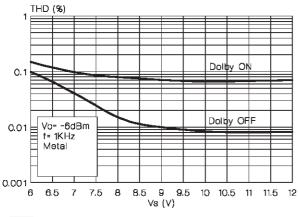


Figure 24: THD vs Frequency

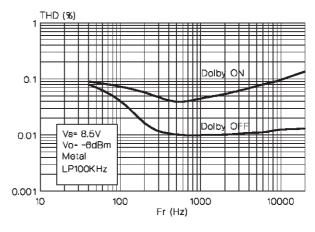


Figure 25: THD vs. Output Signal

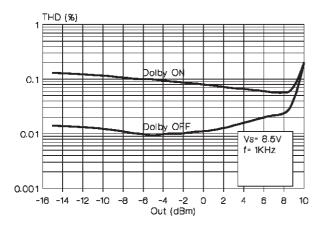


Figure 27: Channel Separation vs. Frequency

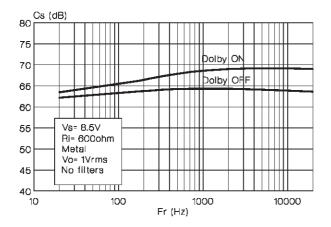


Figure 29: Ripple Rejection vs. Frequency

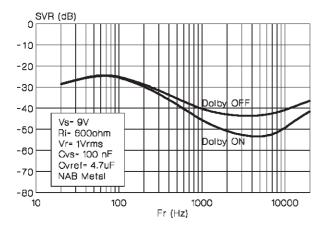


Figure 26: THD+N vs. Frequency

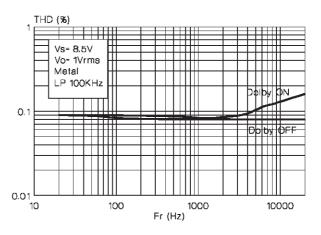


Figure 28: Cross Talk vs. Frequency

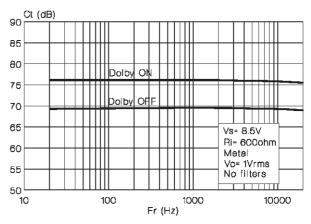


Figure 30: Ripple Rejection vs. Frequency

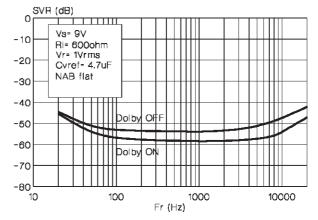


Figure 31: Ripple Rejection vs. Frequency

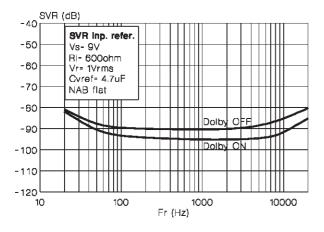


Figure 33: Mute Threshold

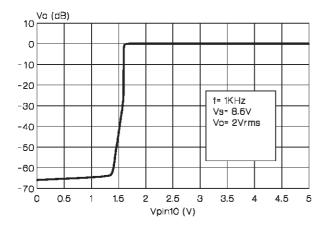


Figure 35: V_{ref} & I_{ref} vs Temperature

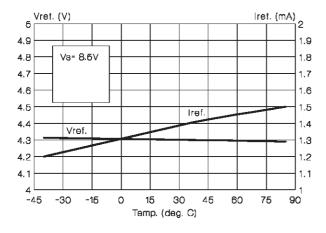


Figure 32: Mute Attenuation vs. Frequency

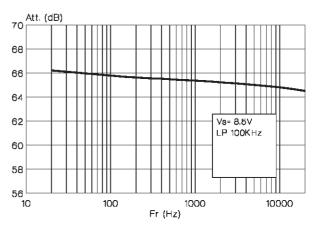


Figure 34: Vref & Iref vs Supply Voltage

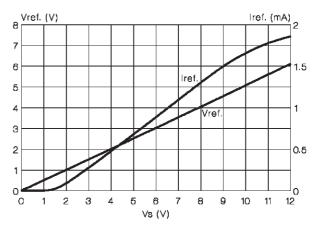


Figure 36: D.C. Voltage pin 13 vs. Supply Voltage

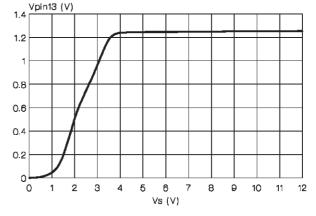


Figure 37: Equalizer Threshold

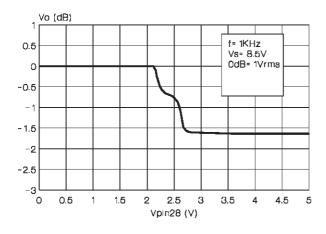


Figure 39: NAB Network

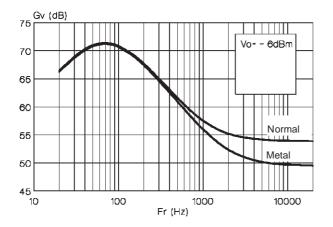


Figure 41: Signaling Handling vs. Supply Voltage

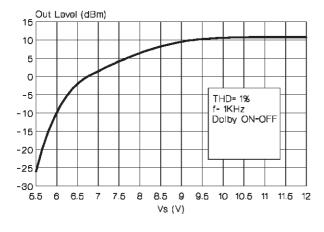


Figure 38: Noise Reduction Threshold

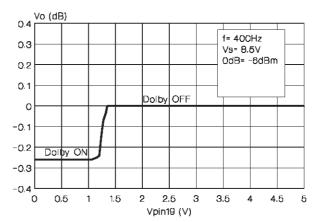


Figure 40: Load Characteristics

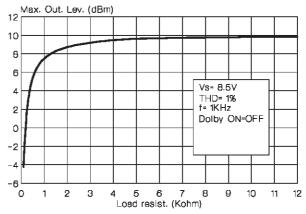


Figure 42: Signal Handling vs. Temperature

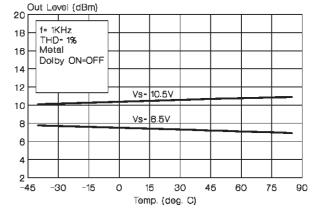


Figure 43: AMS Threshold vs. Frequency

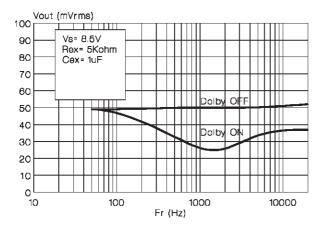


Figure 45: AMS Reset Time vs. Cex

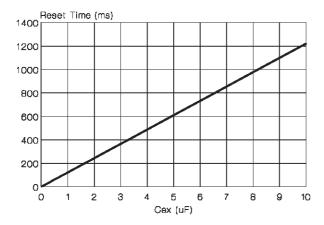


Figure 47: Interprogram Charging Current

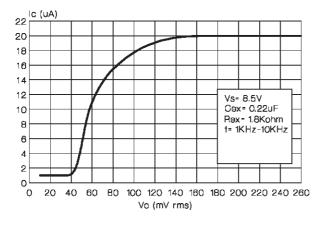


Figure 44: AMS Threshold vs. Rex

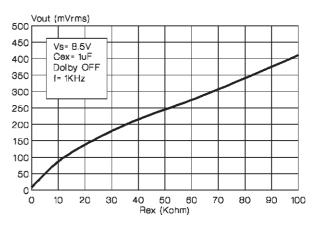


Figure 46: AMS Interprogram vs. C7

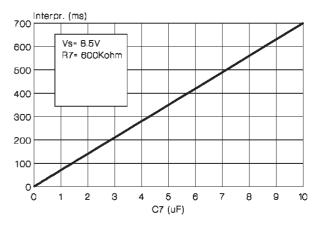


Figure 48: Interspace vs. C9

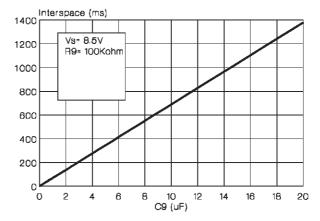
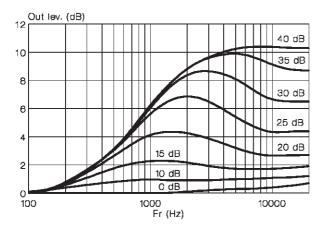
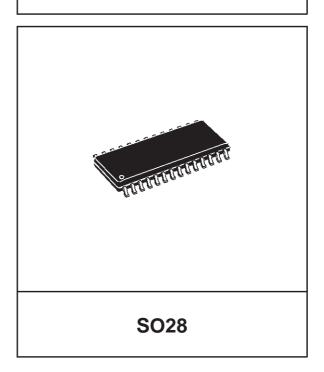


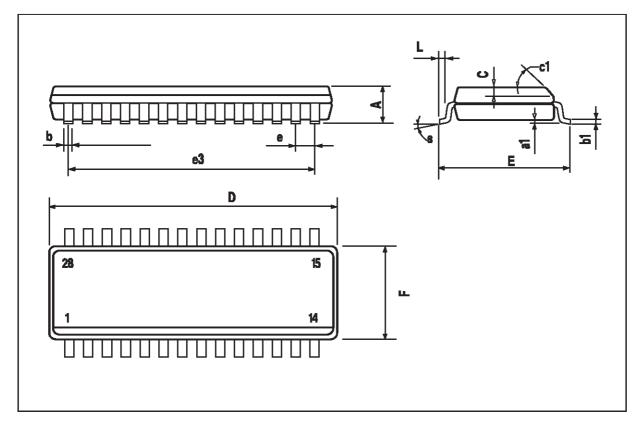
Figure 49: Dolby-B Table



DIM.		mm			inch			
	MIN.	TYP.	MAX.	MIN.	TYP.	MAX.		
А			2.65			0.104		
a1	0.1		0.3	0.004		0.012		
b	0.35		0.49	0.014		0.019		
b1	0.23		0.32	0.009		0.013		
С		0.5			0.020			
c1			45° (typ.)				
D	17.7		18.1	0.697		0.713		
E	10		10.65	0.394		0.419		
е		1.27			0.050			
е3		16.51			0.65			
F	7.4		7.6	0.291		0.299		
L	0.4		1.27	0.016		0.050		
S			8 ° (n	nax.)				

OUTLINE AND MECHANICAL DATA





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